

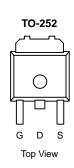
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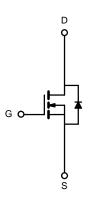
N-Channel 60-V (D-S) MOSFET

| PRODUCT SUMMARY | | | | | |
|----------------------------------|-------------------------------|--------------------|--|--|--|
| $V_{DS}(V)$ $r_{DS(on)}(\Omega)$ | | I _D (A) | | | |
| 60 | 0.033@ V _{GS} = 10 V | 35 | | | |

FEATURES

- DT-Trench Power MOSFET
- 175°C Maximum Junction Temperature
- 100% R_g Tested





N-Channel MOSFET

| ABSOLUTE MAXIMUM RATINGS (T _A = 25°C UNLESS OTHERWISE NOTED) | | | | | |
|---|-----------------------------------|-----------------|------------------|----|--|
| Parameter | Symbol | Limit | Unit | | |
| Drain-Source Voltage | | V _{DS} | 60 | ., | |
| Gate-Source Voltage | | V _{GS} | ±20 | | |
| Continuous Davis Comment /T 4750Ch | T _C = 25°C | | 35 | | |
| Continuous Drain Current (T _J = 175°C) ^b | T _C = 125°C | l _D | 20 | | |
| Pulsed Drain Current | | I _{DM} | 90 | А | |
| Continuous Source Current (Diode Conduction) | I _S | 30 | | | |
| Avalanche Current | I _{AR} | 10 | | | |
| Repetitive Avalanche Energy (Duty Cycle ≤ 1%) | L = 0.1 mH | E _{AR} | 50 | mJ | |
| | T _C = 25°C | _ | 106 ^b | | |
| Maximum Power Dissipation | T _A = 25°C | P _D | 2 ^a | W | |
| Operating Junction and Storage Temperature Range | T _J , T _{stg} | -55 to 175 | °C | | |

| THERMAL RESISTANCE RATINGS | | | | | | |
|----------------------------------|--------------|-------------------|---------|------|------|--|
| Parameter | Symbol | Typical | Maximum | Unit | | |
| | t ≤ 10 sec | _ | 15 | 23 | | |
| Junction-to-Ambient ^a | Steady State | R_{thJA} | 40 | 60 | °C/W | |
| Junction-to-Case | | R _{thJC} | 0.85 | 1.5 | | |

a. Surface Mounted on 1" x1" FR4 Board.b. See SOA curve for voltage derating.



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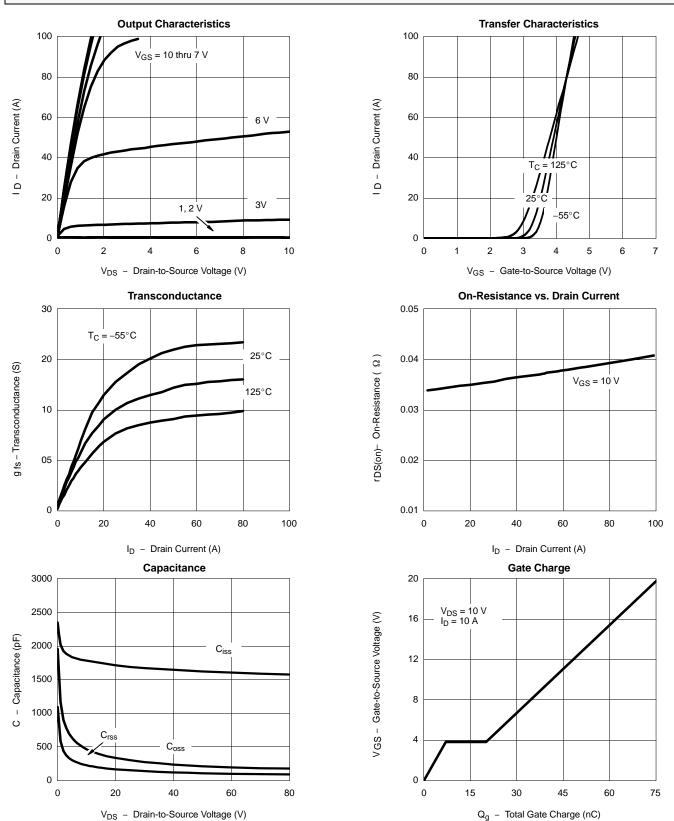
| Parameter | Symbol | Test Condition | Min | Typa | Max | Unit |
|---|----------------------|---|----------|-------|-------|------|
| Static | - | | | 1 | | |
| Drain-Source Breakdown Voltage | V _{(BR)DSS} | $V_{GS} = 0 \text{ V}, I_D = 250 \mu A$ | 60 | | | |
| Gate Threshold Voltage | V _{GS(th)} | $V_{DS} = V_{GS}, I_D = 250 \mu A$ | 1.0 | | 3.0 | - V |
| Gate-Body Leakage | I _{GSS} | V_{DS} = 0 V, V_{GS} = ± 20 V | | | ±100 | nA |
| | | V _{DS} = 60 V, V _{GS} = 0 V | | | 1 | |
| Zero Gate Voltage Drain Current | I _{DSS} | $V_{DS} = 60 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 125 ^{\circ}\text{C}$ | | | 50 | μА |
| | | V _{DS} = 60 V, V _{GS} = 0 V, T _J = 175°C | | | 250 | 1 |
| On-State Drain Current ^b | I _{D(on)} | $V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$ | 10 | | | Α |
| | | V _{GS} = 10 V, I _D = 5 A | | 0.033 | 0.040 | Ω |
| Drain-Source On-State Resistance ^b | r _{DS(on)} | $V_{GS} = 10 \text{ V}, I_D = 5A, T_J = 125^{\circ}\text{C}$ | | 0.042 | 0.050 | |
| | | $V_{GS} = 10 \text{ V}, I_D = 5 \text{ A}, T_J = 175^{\circ}\text{C}$ | | 0.046 | | |
| Forward Transconductance ^b | 9fs | V _{DS} = 15 V, I _D = 5 A | | 23 | | S |
| Dynamic ^a | | | | • | • | |
| Input Capacitance | C _{iss} | | | 1560 | | pF |
| Output Capacitance | C _{oss} | $V_{GS} = 0 \text{ V}, V_{DS} = 25 \text{ V}, F = 1 \text{ MHz}$ | | 370 | | |
| Reverse Transfer Capacitance | C _{rss} | | | 200 | | |
| Total Gate Charge ^c | Qg | | | 42 | 60 | |
| Gate-Source Charge ^c | Q _{gs} | $V_{DS} = 40 \text{ V}, \ V_{GS} = 10 \text{ V}, \ I_D = 10 \text{ A}$ | | 7 | | nC |
| Gate-Drain Charge ^c | Q _{gd} | | | 13 | | 1 |
| Gate Resistance | R _g | | 0.5 | | 2.7 | Ω |
| Turn-On Delay Time ^c | t _{d(on)} | | | 12 | 20 | - ns |
| Rise Time ^c | t _r | $V_{DD} = 40 \text{ V}, R_1 = 1.0 \Omega$ | | 52 | 80 | |
| Turn-Off Delay Time ^c | t _{d(off)} | V_{DD} = 40 V, R_L = 1.0 Ω $I_D \cong$ 10 A, V_{GEN} = 10 V, R_g = 2.5 Ω | | 25 | 38 | |
| Fall Time ^c | t _f | | | 10 | 15 | |
| Source-Drain Diode Ratings ar | d Characteristi | c (T _C = 25°C) | | | | |
| Pulsed Current | I _{SM} | | | | 90 | А |
| Diode Forward Voltage ^b | V _{SD} | I _F = 10 A, V _{GS} = 0 V | | 1.0 | 1.5 | V |
| Source-Drain Reverse Recovery Time | t _{rr} | I _F = 10 A, di/dt = 100 A/μs | <u> </u> | 45 | 70 | ns |

- Notes a. Guaranteed by design, not subject to production testing. b. Pulse test; pulse width $\leq 300~\mu s$, duty cycle $\leq 2\%$. c. Independent of operating temperature.





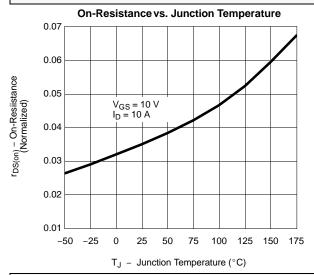
TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)

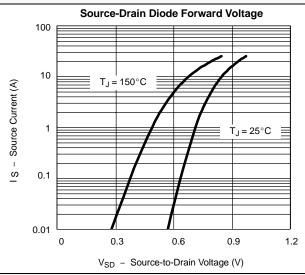




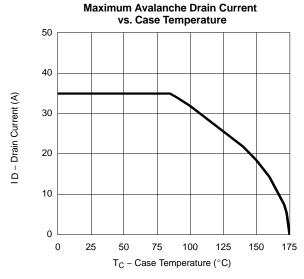


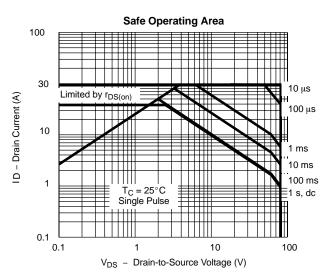
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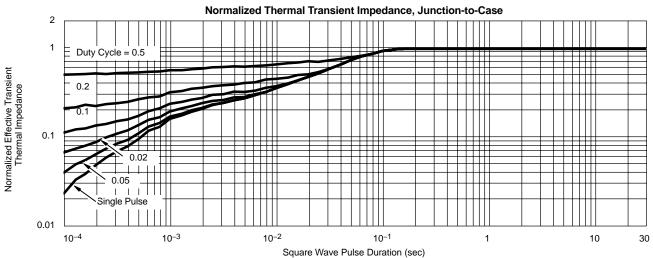




THERMAL RATINGS



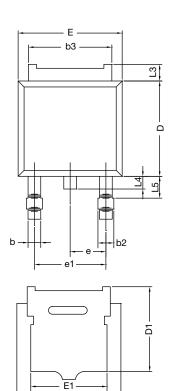


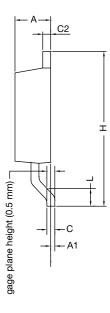






TO-252AA CASE OUTLINE





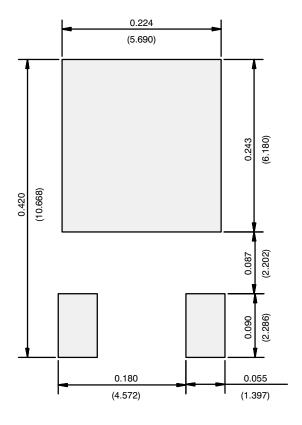
| | MILLIN | METERS | INCHES | | |
|---------------------------------|----------|--------|-----------|-------|--|
| DIM. | MIN. | MAX. | MIN. | MAX. | |
| Α | 2.18 | 2.38 | 0.086 | 0.094 | |
| A1 | - | 0.127 | - | 0.005 | |
| b | 0.64 | 0.88 | 0.025 | 0.035 | |
| b2 | 0.76 | 1.14 | 0.030 | 0.045 | |
| b3 | 4.95 | 5.46 | 0.195 | 0.215 | |
| С | 0.46 | 0.61 | 0.018 | 0.024 | |
| C2 | 0.46 | 0.89 | 0.018 | 0.035 | |
| D | 5.97 | 6.22 | 0.235 | 0.245 | |
| D1 | 5.21 | - | 0.205 | - | |
| Е | 6.35 | 6.73 | 0.250 | 0.265 | |
| E1 | 4.32 | - | 0.170 | - | |
| Н | 9.40 | 10.41 | 0.370 | 0.410 | |
| е | 2.28 | BSC | 0.090 BSC | | |
| e1 | 4.56 BSC | | 0.180 BSC | | |
| L | 1.40 | 1.78 | 0.055 | 0.070 | |
| L3 | 0.89 | 1.27 | 0.035 | 0.050 | |
| L4 | - | 1.02 | - | 0.040 | |
| L5 | 1.14 | 1.52 | 0.045 | 0.060 | |
| ECN: X12-0247-Rev. M, 24-Dec-12 | | | | | |

DWG: 5347 Note

• Dimension L3 is for reference only.



RECOMMENDED MINIMUM PADS FOR DPAK (TO-252)



Recommended Minimum Pads Dimensions in Inches/(mm)

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